

MM5ZxxxT1G Series, SZMM5ZxxxT1G Series

Zener Voltage Regulators

300 mW SOD-523 Surface Mount

This series of Zener diodes is packaged in a SOD-523 surface mount package. They are designed to provide voltage regulation protection and are especially attractive in situations where space is at a premium. They are well suited for applications such as cellular phones, hand held portables, and high density PC boards.

Specification Features:

- Standard Zener Breakdown Voltage Range – 2.4 V to 75 V
- Steady State Power Rating of 300 mW
- Small Body Outline Dimensions:
0.047" x 0.032" (1.20 mm x 0.80 mm)
- Low Body Height: 0.028" (0.7 mm)
- ESD Rating of Class 3 (> 16 kV) per Human Body Model
- AEC-Q101 Qualified and PPAP Capable – SZMM5ZxxxT1G
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- These are Pb-Free Devices*

Mechanical Characteristics:

CASE: Void-free, transfer-molded, thermosetting plastic

Epoxy Meets UL 94 V-0

LEAD FINISH: 100% Matte Sn (Tin)

MOUNTING POSITION: Any

QUALIFIED MAX REFLOW TEMPERATURE: 260°C

Device Meets MSL 1 Requirements

MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, @ T _A = 25°C	P _D	300	mW
Thermal Resistance, Junction-to-Ambient (Note 1)	R _{θJA}	390	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-65 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. EIA/JEDEC51.3 board design and EIA/JEDEC51.2 still air test method (25 mm², 2 oz., 3.8 μm plating).

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

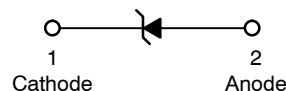


ON Semiconductor®

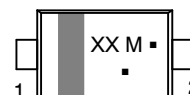
<http://onsemi.com>



SOD-523
CASE 502
STYLE 1



MARKING DIAGRAM



XX = Specific Device Code
M = Date Code*
▪ = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping†
MM5ZxxxT1G	SOD-523 (Pb-Free)	3,000 / Tape & Reel
SZMM5ZxxxT1G	SOD-523 (Pb-Free)	3,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

DEVICE MARKING INFORMATION

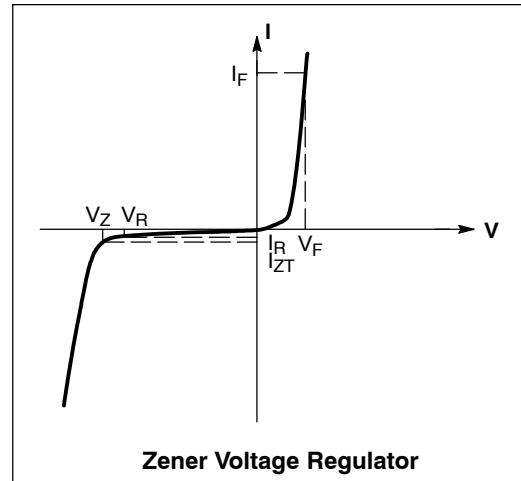
See specific marking information in the device marking column of the Electrical Characteristics tables starting on page 3 of this data sheet.

MM5ZxxxT1G Series, SZMM5ZxxxT1G Series

ELECTRICAL CHARACTERISTICS

($T_A = 25^\circ\text{C}$ unless otherwise noted,
 $V_F = 0.9\text{ V Max. @ } I_F = 10\text{ mA}$ for all types)

Symbol	Parameter
V_Z	Reverse Zener Voltage @ I_{ZT}
I_{ZT}	Reverse Current
Z_{ZT}	Maximum Zener Impedance @ I_{ZT}
I_{ZK}	Reverse Current
Z_{ZK}	Maximum Zener Impedance @ I_{ZK}
I_R	Reverse Leakage Current @ V_R
V_R	Reverse Voltage
I_F	Forward Current
V_F	Forward Voltage @ I_F
ΘV_Z	Maximum Temperature Coefficient of V_Z
C	Max. Capacitance @ $V_R = 0$ and $f = 1\text{ MHz}$



TYPICAL CHARACTERISTICS

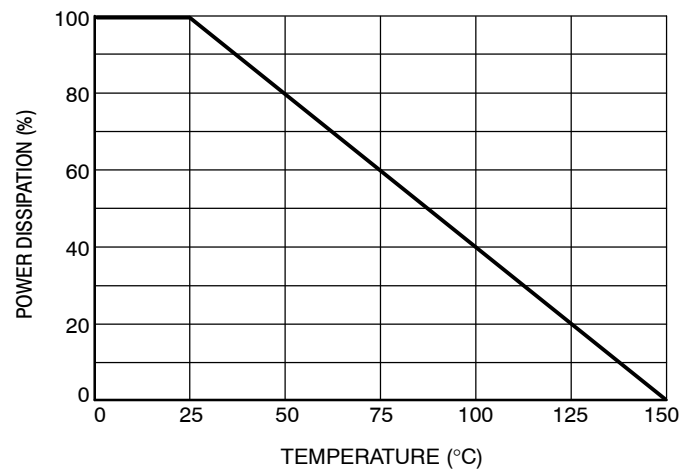


Figure 1. Steady State Power Derating

MM5ZxxxT1G Series, SZMM5ZxxxT1G Series

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted, $V_F = 0.9\text{ V}$ Max. @ $I_F = 10\text{ mA}$ for all types)

Device*	Device Marking	Zener Voltage (Note 1)				Zener Impedance			Leakage Current		θ_{V_Z} (mV/k) @ I_{ZT}		C @ $V_R = 0$ f = 1 MHz
		V_Z (Volts)			@ I_{ZT}	Z_{ZT} @ I_{ZT}	Z_{ZK} @ I_{ZK}	I_R @ V_R					
		Min	Nom	Max	mA	Ω	Ω	mA	μA	Volts	Min	Max	pF
MM5Z2V4T1G	00	2.2	2.4	2.6	5	100	1000	1.0	50	1.0	-3.5	0	450
MM5Z2V7T1G	01	2.5	2.7	2.9	5	100	1000	1.0	20	1.0	-3.5	0	450
MM5Z3V0T1G	02	2.8	3.0	3.2	5	100	1000	1.0	10	1.0	-3.5	0	450
MM5Z3V3T1G	05	3.1	3.3	3.5	5	95	1000	1.0	5	1.0	-3.5	0	450
MM5Z3V6T1G	06	3.4	3.6	3.8	5	90	1000	1.0	5	1.0	-3.5	0	450
MM5Z4V3T1G	08	4.0	4.3	4.6	5	90	1000	1.0	3	1.0	-3.5	0	450
MM5Z4V7T1G	09	4.4	4.7	5.0	5	80	800	1.0	3	2.0	-3.5	0.2	260
MM5Z5V1T1G	0A	4.8	5.1	5.4	5	60	500	1.0	2	2.0	-2.7	1.2	225
MM5Z5V6T1G	0C	5.2	5.6	6.0	5	40	200	1.0	1	2.0	-2.0	2.5	200
MM5Z6V2T1G	0E	5.8	6.2	6.6	5	10	100	1.0	3	4.0	0.4	3.7	185
MM5Z6V8T1G	0F	6.4	6.8	7.2	5	15	160	1.0	2	4.0	1.2	4.5	155
MM5Z7V5T1G	0G	7.0	7.5	7.9	5	15	160	1.0	1	5.0	2.5	5.3	140
MM5Z8V2T1G	0H	7.7	8.2	8.7	5	15	160	1.0	0.7	5.0	3.2	6.2	135
MM5Z9V1T1G	0K	8.5	9.1	9.6	5	15	160	1.0	0.2	7.0	3.8	7.0	130
MM5Z10VT1G	0L	9.4	10	10.6	5	20	160	1.0	0.1	8.0	4.5	8.0	130
MM5Z11VT1G	0M	10.4	11	11.6	5	20	160	1.0	0.1	8.0	5.4	9.0	130
MM5Z12VT1G	0N	11.4	12	12.7	5	25	80	1.0	0.1	8.0	6.0	10	130
MM5Z13VT1G	0P	12.4	13.25	14.1	5	30	80	1.0	0.1	8.0	7.0	11	120
MM5Z15VT1G	0T	14.3	15	15.8	5	30	80	1.0	0.05	10.5	9.2	13	110
MM5Z16VT1G	0U	15.3	16.2	17.1	5	40	80	1.0	0.05	11.2	10.4	14	105
MM5Z18VT1G	0W	16.8	18	19.1	5	45	80	1.0	0.05	12.6	12.4	16	100
MM5Z20VT1G	0Z	18.8	20	21.2	5	55	100	1.0	0.05	14.0	14.4	18	85
MM5Z22VT1G	10	20.8	22	23.3	5	55	100	1.0	0.05	15.4	16.4	20	85
MM5Z24VT1G	11	22.8	24.2	25.6	5	70	120	1.0	0.05	16.8	18.4	22	80
MM5Z27VT1G	12	25.1	27	28.9	2	80	300	1.0	0.05	18.9	21.4	25.3	70
MM5Z30VT1G	14	28	30	32	2	80	300	1.0	0.05	21.0	24.4	29.4	70
MM5Z33VT1G	18	31	33	35	2	80	300	1.0	0.05	23.2	27.4	33.4	70
MM5Z36VT1G	19	34	36	38	2	90	500	1.0	0.05	25.2	30.4	37.4	70
MM5Z39VT1G	20	37	39	41	2	130	500	1.0	0.05	27.3	33.4	41.2	45
MM5Z43VT1G	21	40	43	46	2	150	500	1.0	0.05	30.1	37.6	46.6	40
MM5Z47VT1G	1A	44	47	50	2	170	500	1.0	0.05	32.9	42.0	51.8	40
MM5Z51VT1G	1C	48	51	54	2	180	500	1.0	0.05	35.7	46.6	57.2	40
MM5Z56VT1G	1D	52	56	60	2	200	500	1.0	0.05	39.2	52.2	63.8	40
MM5Z62VT1G	1E	58	62	66	2	215	500	1.0	0.05	43.4	58.8	71.6	35
MM5Z68VT1G	1F	64	68	72	2	240	500	1.0	0.05	47.6	65.6	79.8	35
MM5Z75VT1G	1G	70	75	79	2	255	500	1.0	0.05	52.5	73.4	88.6	35

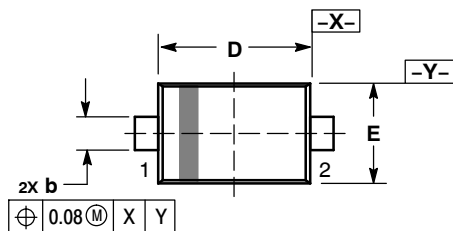
1. Zener voltage is measured with a pulse test current I_Z at an ambient temperature of 25°C .

*Include SZ-prefix devices where applicable.

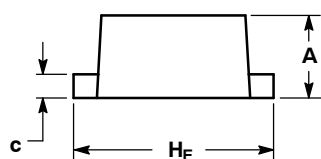
MM5ZxxxT1G Series, SZMM5ZxxxT1G Series

PACKAGE DIMENSIONS

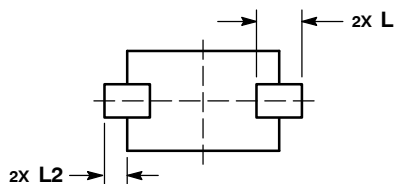
SOD-523
CASE 502
ISSUE E



TOP VIEW



SIDE VIEW



BOTTOM VIEW

NOTES:

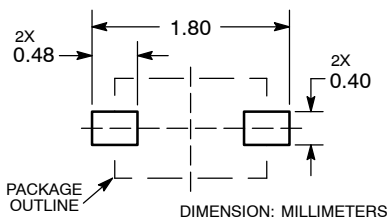
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

DIM	MILLIMETERS		
	MIN	NOM	MAX
A	0.50	0.60	0.70
b	0.25	0.30	0.35
c	0.07	0.14	0.20
D	1.10	1.20	1.30
E	0.70	0.80	0.90
H _E	1.50	1.60	1.70
L	0.30 REF		
L2	0.15	0.20	0.25

STYLE 1:

- PIN 1. CATHODE (POLARITY BAND)
2. ANODE

RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and  are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor
P.O. Box 5163, Denver, Colorado 80217 USA
Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada
Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free
USA/Canada
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910
Japan Customer Focus Center
Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: <http://www.onsemi.com/orderlit>

For additional information, please contact your local Sales Representative

MM5Z2V4T1/D

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9